ECEN325 Ref Sheet © Josh Wright September 23, 2017

Metric Prefixes							
peta	Ρ	10^{15}	1 000 000 000 000 000				
tera	Τ	10^{12}	1 000 000 000 000				
giga	G	10^{9}	1 000 000 000				
mega	Μ	10^{6}	1 000 000				
kilo	k	10^{3}	1 000				
hecto	h	10^{2}	100				
deca	da	10^{1}	10				
one		10^{0}	1				
deci	d	10^{-1}	0.1				
centi	c	10^{-2}	0.01				
milli	m	10^{-3}	0.001				
micro	μ	10^{-6}	0.000 001				
nano	n	10^{-9}	0.000 000 001				
pico	р	10^{-12}	0.000 000 000 001				
femto	f	10^{-15}	0.000 000 000 000 001				
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Ohm's Law
$$V = IR$$
, $I = \frac{V}{R}$, $R = \frac{V}{I}$

Battery Symbol

The side with the longer line is the positive side

Complex Numbers

- $\bullet \frac{1}{i} = -i$
- $\bullet \sqrt[n]{z} = \sqrt[n]{r}e^{\frac{\theta}{n} + \frac{2k\pi}{n}} \text{ for } n \in N^* \text{ (ints } \ge 0)$ $\bullet e^{j\theta} = \cos(\theta) + j\sin(\theta) \mid e^{-j\theta} = \cos(\theta) j\sin(\theta)$ $\bullet \cos(\theta) = \frac{1}{2}(e^{j\theta} + e^{-j\theta}) \mid \sin(\theta) = \frac{1}{2j}(e^{j\theta} e^{-j\theta})$
- normalized: $sinc(t) = \frac{\sin(\pi t)}{\pi t}$
- $\bullet \left| \frac{a}{b} \right| = \frac{|a|}{|b|}$

Trig

$$\cos^2(2a) = \cos^2(a) - \sin^2(a) = 2\cos^2(a) - 1 = 1 - 2\sin^2(a)$$

$$\cos^2(a) + \sin^2(a) = 1$$

$$\cos^2(a) = \frac{1}{2}(1 + \cos(2a))$$

$$\sin^2(a) = \frac{1}{2}(1 - \cos(2a))$$

Voltage Division between two non-zero points

(superposition)

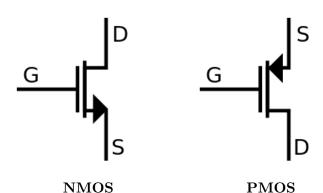
 $V_{DD}
ightarrow R_1
ightarrow V_1
ightarrow R_2
ightarrow V_{EE} \ V_1 = V_{DD} rac{R_2}{R_1 + R_2} + V_{EE} rac{R_1}{R_1 + R_2}$

AC Resistors and Capacitors

$$R||\frac{1}{Cs} = \frac{R\frac{1}{Cs}}{R + \frac{1}{Cs}} = \frac{R}{RCs + 1}$$

$$\frac{R}{R + \frac{1}{Cs}} = \frac{RCs}{RCs + 1} = \frac{s}{s + \frac{1}{RC}}$$
$$\frac{\frac{1}{Cs}}{R + \frac{1}{Cs}} = \frac{1}{RCs + 1}$$

MOS



MOS DC Biasing

- this is all for NMOS. PMOS is backward $\beta = k'_n(\frac{W}{L})$ cutoff: $V_{GS} < V_{th}$

- $*I_D = 0$ triode (linear): $V_{DS} < V_{GS} V_{th}$

$$*I_D = k_n' \frac{W}{L} \left((V_{GS} - V_{th}) V_{DS} - \frac{V_{DS}^2}{2} \right)$$

- active (saturation): $V_{DS} > V_{GS} V_{th}$ * $I_D = \frac{k'_n}{2} \frac{W}{L} (V_{GS} V_{th})^2$ * overdrive voltage $V_{ov} = V_{GS} V_{th}$ to show it's active: show that $V_{DS} > V_{ov}$ (or

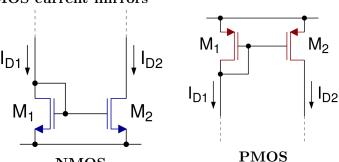
 $V_{DS} > V_{GS} - V_{th}$)
MOS Small Signal

	$\frac{V_o}{V_g}$	R_i	R_o				
CS	$-\frac{R_D R_L}{\frac{1}{g_m} + R_S}$	$R_{G1} R_{G2}$	R_D				
CG	$R_D R_L$	_1_	Rp				

I			
CD	$\frac{R_L}{\frac{1}{g_m} + R_L}$	$R_{G1} R_{G2}$	$\frac{1}{g_m}$

- $\bullet g_m = k' \frac{W}{L} (V_{GS} V_t) = k' \frac{W}{L} (V_{ov}) = \sqrt{2k' \frac{W}{L} I_D}$
- CS: Common Source
- CG: Common Gate
- CD: Common Drain (buffer)
- $\angle \frac{a}{b} = \angle a \angle b$ apparently, when calculating the max gain of the frequency response, it is OK to just use the part of he equation that doesn't depend on s

MOS current mirrors



NMOS
• where M1 is the transistor with base shorted to ground (the reference branch)

 $\bullet \stackrel{I_{D1}}{I_{D2}} = \frac{(W/L)_1}{(W/L)_2} \text{ or } I_{D2} = \frac{(W/L)_2}{(W/L)_1} I_{D1}$

Bode Plots

- magnitude is plotted in dB: $|T(j\omega)|_{dB} = 20\log_{10}|T(j\omega)|$
- starts on y-axis at DC offset with slope 0
- just add together the bode plots of each individual pole, zero, and the DC offset
- poles always slope down, zeros slope up (applies for both magnitude and phase)
- dec=decade, e.g. from 10^0 to 10^1
- magnitude:
- *Pole/Zero at origin: constant slope $\pm 20db/dec$ for all ω ; 0dB at $\omega = 10^0 = 1$
- *Pole/Zero at ω_0 : 0 for $\omega < \omega_0$ slope $\pm 20 \frac{db}{dec}$ after

*Constant C: constant line at $20 \log_{10}(|C|)$

*Pole at origin: constant $-\frac{\pi}{2}$ or -90°

*Zero at origin: constant $+\frac{\pi}{2}$ or $+90^{\circ}$

*Pole/Zero at ω_0 :

0 for $\omega < \frac{\omega_0}{10}$

slope linearly ($\pm 45^{\circ}/dec$) until $10\omega_0$

0 slope for $\omega > 10\omega_0$

*Constant C: no effect (0 for all ω)

• Prof wants us to actually show the -3dB drop curve, not just a straight intersection

• on the x-axis of the bode plot you need to plot frequency in Hz, so take $s = j\omega$ and divide by 2π

Solving systems with Op Amps

• only applies if the op-amp has feedback

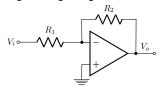
• step 0: if the op amp is ideal, write out ideal properties:

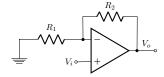
 $V_{+}^{I} = V_{-}$ $V_{+}^{I} = V_{-}$ $V_{+}^{I} = 0, I_{+}^{I} = 0$ $V_{+}^{I} = 0, I_{+}^{I} = 0$

• avoid doing KCL/KVL directly on the output node of the op amp

• ignore resistors from a point at 0V to ground

Op Amp Equations





Inverting Amplifier

Non-Inverting Amplifier

• ideal open-loop behavior: $(V_p - V_n) > 0 \rightarrow V_o = V_{DD}$

• general form: $T(s) = \frac{K_0}{1 + \frac{s}{\omega_0}}$

 $*T(0) = K_0$: DC offset. For these simple ones, it's equal to ideal response

 $*\omega_0 = \frac{\omega_t}{1 + R_2/R_1}$

• inverting op amp:
*ideal:
$$T(s) = \frac{V_o}{V_i} = -\frac{R_2}{R_1}$$

* non-ideal:
$$T(s) = \frac{V_i}{V_i} = \frac{R_1}{1 + \frac{1 + R_2/R_1}{A(s)}} = \frac{-R_2/R_1}{1 + \frac{s}{W_0}} = \frac{-R_2/R_1}{1 + \frac{s}{W_0}} = \frac{-R_2/R_1}{1 + \frac{s}{W_0}}$$
• non-inverting op-amp:

• non-inverting op-amp: *ideal: $T(s) = \frac{V_o}{V_i} = 1 + \frac{R_2}{R_1}$

*non-ideal:
$$T(s) = \frac{V_o}{V_i} = \frac{1 + R_2/R_1}{1 + \frac{1 + R_2/R_1}{A(s)}} = \frac{1 + R_2/R_1}{1 + \frac{s}{(\frac{\omega_t}{1 + R_2/R_1})}} = \frac{1 + R_2/R_1}{1 + \frac{s}{\omega_0}}$$

RC Filter

• Transmission Function: $T(s) = \frac{V_o(s)}{V_i(s)}$

• Corner frequency: frequency s at which $T(s) = \frac{1}{\sqrt{2}}$

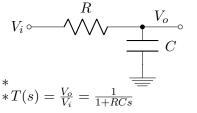
• for simple circuit: ground \rightarrow source $\rightarrow R \rightarrow C \rightarrow$ ground

$$*T(s) = \frac{1}{1+RCs}$$

$$|T(j\omega)| = \frac{1}{\sqrt{1+R^2C^2s^2}}$$

$$|\angle T(j\omega)| = \frac{1}{\sqrt{1+R^2C^2s^2}}$$

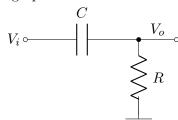
• low pass



*corner frequency: $s = \frac{1}{RC}$ (also pole)

* pole: $\frac{1}{RC}$

high pass



 $*T(s) = \frac{V_o}{V_i} = \frac{RCs}{1 + RCs}$

* zero: s=0, pole: $s=\frac{1}{RC}$